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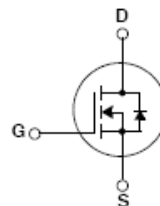
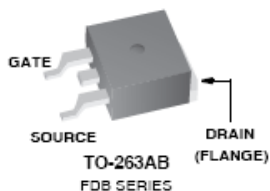
N-Channel Logic Level PowerTrench® MOSFET 30V, 80A, 2.6mΩ

Features

- $R_{DS(ON)} = 1.9\text{m}\Omega$ (Typ), $V_{GS} = 5\text{V}$, $I_D = 80\text{A}$
- $Q_{g(5)} = 89\text{nC}$ (Typ), $V_{GS} = 5\text{V}$
- Low Miller Charge
- Low Q_{RR} Body Diode
- UIS Capability (Single Pulse and Repetitive Pulse)
- RoHS Compliant

Applications

- DC-DC Converters



MOSFET Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
V_{DSS}	Drain to Source Voltage	30	V
V_{GS}	Gate to Source Voltage	± 20	V
I_D	Drain Current Continuous ($V_{GS} = 10\text{V}$, $T_C < 163^\circ\text{C}$)	80	A
	Continuous ($V_{GS} = 5\text{V}$, $T_C < 162^\circ\text{C}$)	80	A
	Continuous ($V_{GS} = 10\text{V}$, $T_C = 25^\circ\text{C}$, with $R_{\theta JA} = 43^\circ\text{C/W}$)	31	A
	Pulsed	Figure 4	A
E_{AS}	Single Pulse Avalanche Energy (Note 1)	947	mJ
P_D	Power Dissipation	254	W
	Derate above 25°C	1.7	W/ $^\circ\text{C}$
T_J, T_{STG}	Operating and Storage Temperature	-55 to +175	$^\circ\text{C}$

Thermal Characteristics

$R_{\theta JC}$	Thermal Resistance Junction to Case	0.59	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient (Note 2)	62	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance Junction to Ambient TO-263, 1in ² copper pad area	43	$^\circ\text{C/W}$

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDB8860	FDB8860	TO-263AB	330mm	24mm	800units

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Off Characteristics

BV_{DSS}	Drain to Source Breakdown Voltage	$I_D = 1\text{mA}$, $V_{GS} = 0\text{V}$	30	-	-	V
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24\text{V}$ $V_{GS} = 0\text{V}$ $T_J = 150^\circ\text{C}$	-	-	1	μA
I_{GSS}	Gate to Source Leakage Current	$V_{GS} = \pm 20\text{V}$	-	-	± 100	nA

On Characteristics

$V_{GS(th)}$	Gate to Source Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 250\mu\text{A}$	1	1.7	3	V
$R_{DS(on)}$	Drain to Source On Resistance	$I_D = 80\text{A}$, $V_{GS} = 10\text{V}$	-	1.6	2.3	m Ω
		$I_D = 80\text{A}$, $V_{GS} = 5\text{V}$	-	1.9	2.6	
		$I_D = 80\text{A}$, $V_{GS} = 4.5\text{V}$	-	2.1	2.7	
		$I_D = 80\text{A}$, $V_{GS} = 10\text{V}$, $T_J = 175^\circ\text{C}$	-	2.5	3.6	

Dynamic Characteristics

C _{ISS}	Input Capacitance	V _{DS} = 15V, V _{GS} = 0V, f = 1MHz		-	9460	12585	pF
C _{OSS}	Output Capacitance			-	1710	2275	pF
C _{RSS}	Reverse Transfer Capacitance			-	1050	1575	pF
R _G	Gate Resistance	f = 1MHz		-	1.8	-	Ω
Q _{g(TOT)}	Total Gate Charge at 10V	V _{GS} = 0V to 10V	V _{DD} = 15V I _D = 80A I _g = 1.0mA	-	165	214	nC
Q _{g(5)}	Total Gate Charge at 5V	V _{GS} = 0V to 5V		-	89	115	nC
Q _{g(TH)}	Threshold Gate Charge	V _{GS} = 0V to 1V		-	9.1	12	nC
Q _{gs}	Gate to Source Gate Charge			-	26	-	nC
Q _{gs2}	Gate Charge Threshold to Plateau			-	18	-	nC
Q _{gd}	Gate to Drain “Miller” Charge			-	33	-	nC

Electrical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
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Switching Characteristics

$t_{(on)}$	Turn-On Time	$V_{DD} = 15\text{V}, I_D = 80\text{A}$ $V_{GS} = 5\text{V}, R_{GS} = 1\Omega$	-	-	340	ns
$t_{d(on)}$	Turn-On Delay Time		-	14	-	ns
t_r	Turn-On Rise Time		-	213	-	ns
$t_{d(off)}$	Turn-Off Delay Time		-	79	-	ns
t_f	Turn-Off Fall Time		-	49	-	ns
t_{off}	Turn-Off Time		-	-	192	ns

Drain-Source Diode Characteristics

V_{SD}	Source to Drain Diode Voltage	$I_{SD} = 80\text{A}$	-	-	1.25	V
		$I_{SD} = 40\text{A}$	-	-	1.0	V
t_{rr}	Reverse Recovery Time	$I_{SD} = 80\text{A}, dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	-	43	ns
Q_{rr}	Reverse Recovery Charge	$I_{SD} = 80\text{A}, dI_{SD}/dt = 100\text{A}/\mu\text{s}$	-	-	29	nC

Notes:1: Starting $T_J = 25^\circ\text{C}$, $L = 0.47\text{mH}$, $I_{AS} = 64\text{A}$, $V_{DD} = 30\text{V}$, $V_{GS} = 10\text{V}$.

2: Pulse width = 100s

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

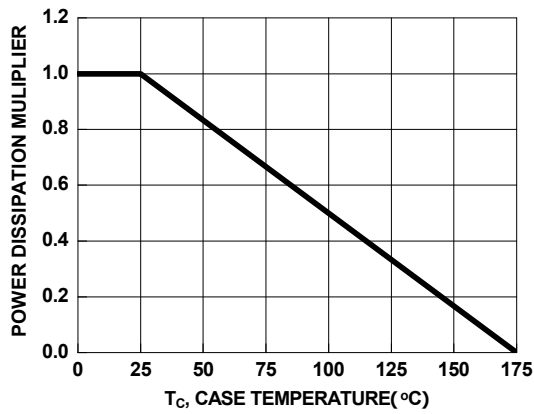


Figure 1. Normalized Power Dissipation vs Case Temperature

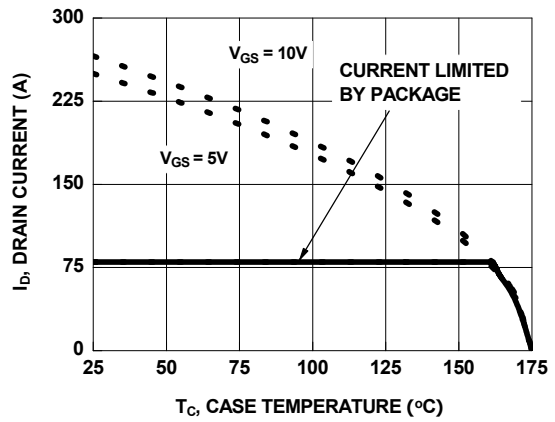


Figure 2. Maximum Continuous Drain Current vs Case Temperature

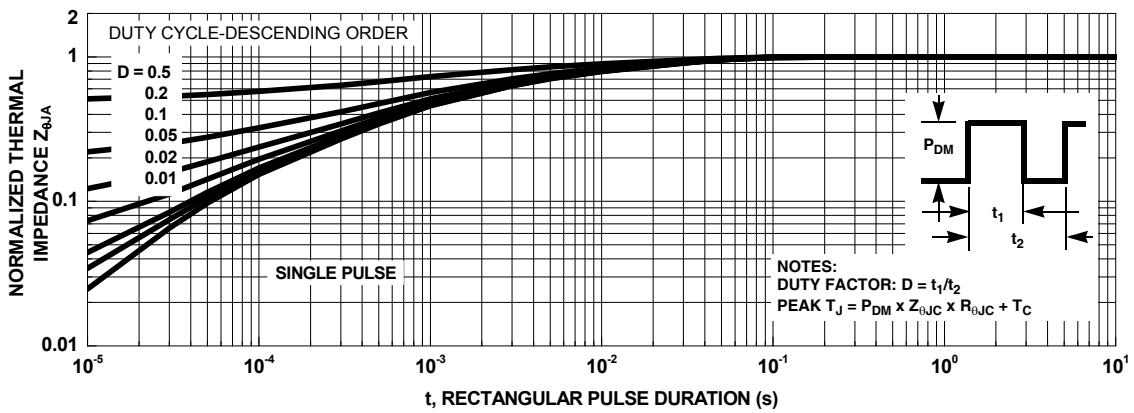


Figure 3. Normalized Maximum Transient Thermal Impedance

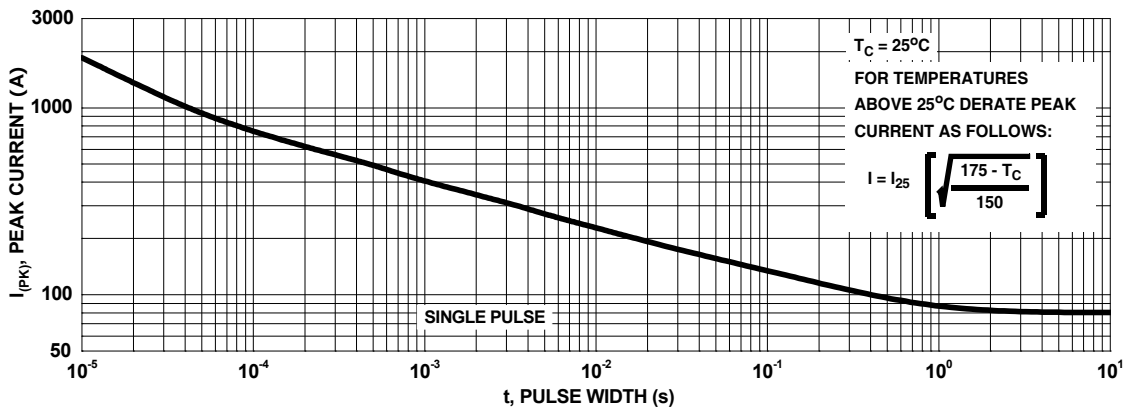


Figure 4. Peak Current Capability

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

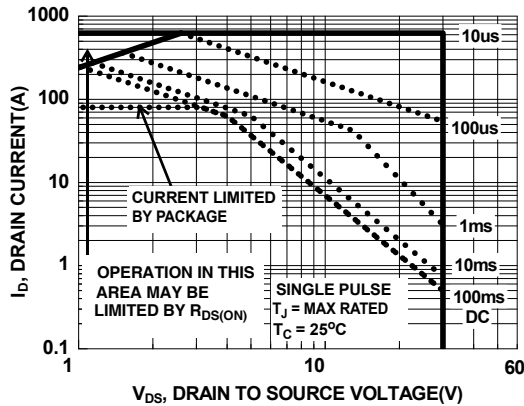
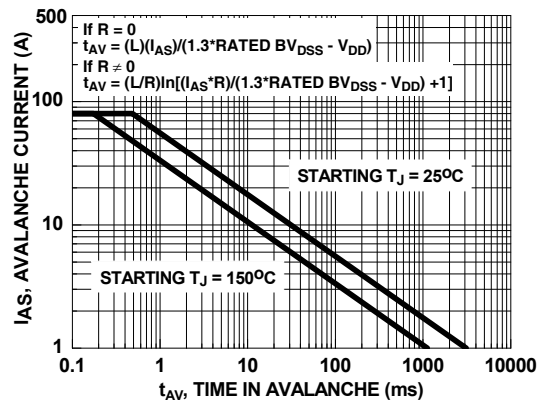


Figure 5. Forward Bias Safe Operating Area



NOTE: Refer to Fairchild Application Notes AN7514 and AN7515

Figure 6. Unclamped Inductive Switching Capability

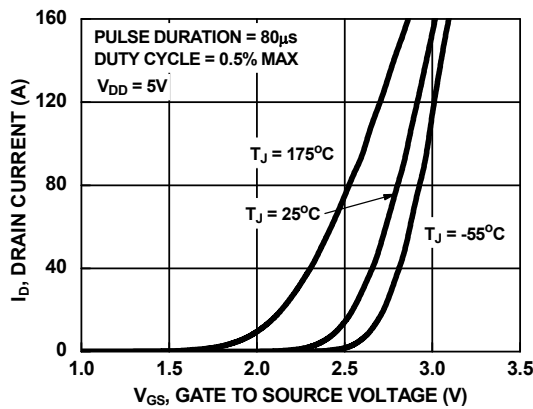


Figure 7. Transfer Characteristics

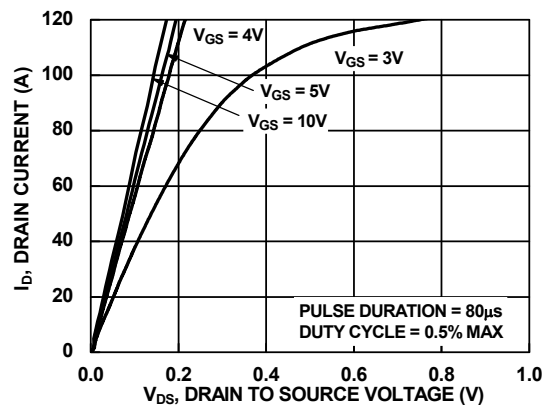


Figure 8. Saturation Characteristics

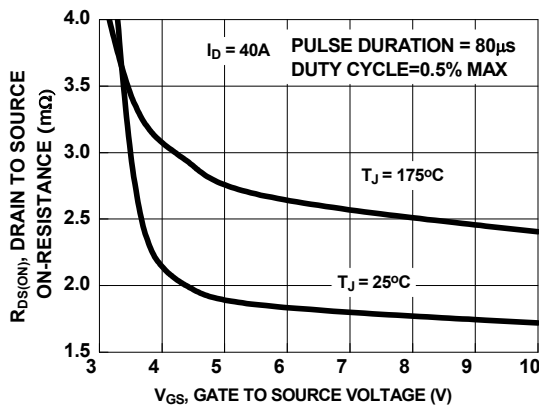


Figure 9. Drain to Source On-Resistance Variation vs Gate to Source Voltage

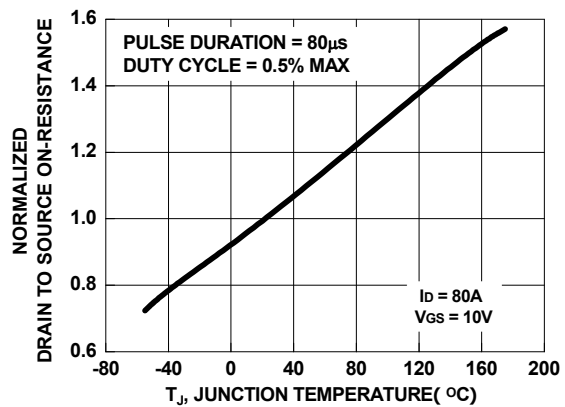


Figure 10. Normalized Drain to Source On-Resistance vs Junction Temperature

Typical Characteristics $T_J = 25^\circ\text{C}$ unless otherwise noted

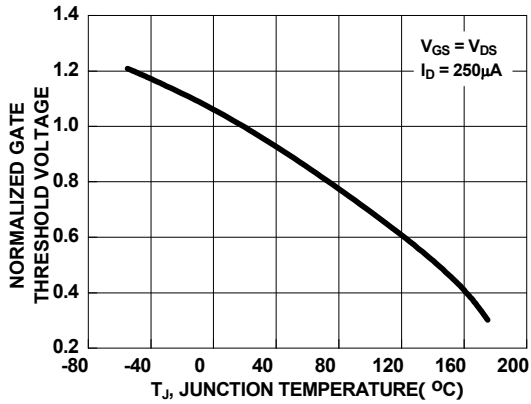


Figure 11. Normalized Gate Threshold Voltage vs Junction Temperature

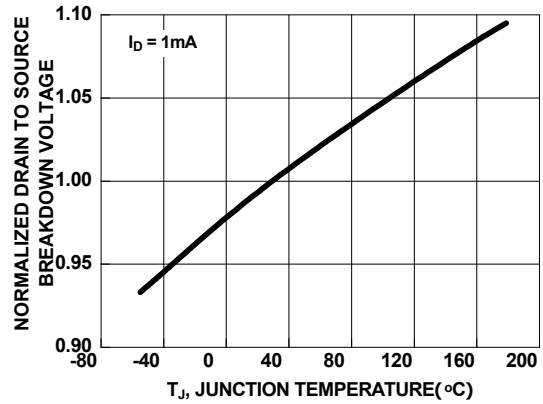


Figure 12. Normalized Drain to Source Breakdown Voltage vs Junction Temperature

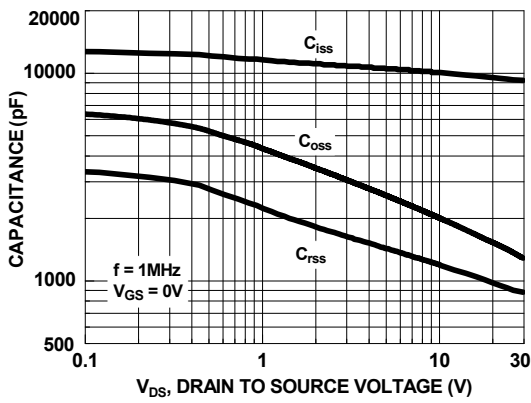


Figure 13. Capacitance vs Drain to Source Voltage

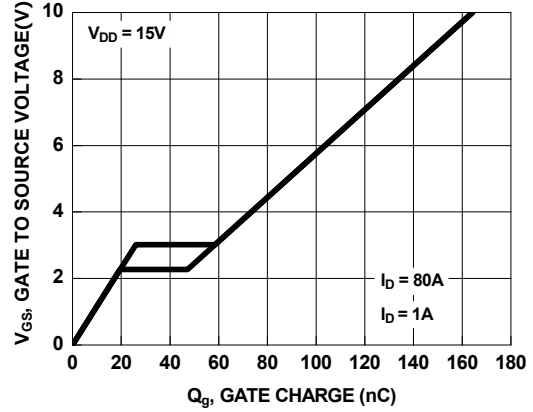


Figure 14. Gate Charge vs Gate to Source Voltage



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